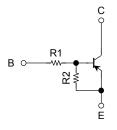
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN2101FS,RN2102FS,RN2103FS RN2104FS,RN2105FS,RN2106FS

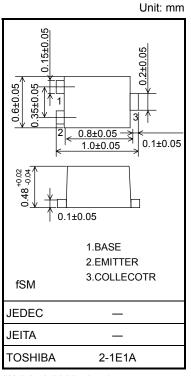
Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- Incorporating a bias resistor into a transistor reduces parts count.
 Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Complementary to RN1101FS~RN1106FS

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2101FS	4.7	4.7
RN2102FS	10	10
RN2103FS	22	22
RN2104FS	47	47
RN2105FS	2.2	47
RN2106FS	4.7	47



Weight: 0.0006g (typ.)

Maximum Ratings (Ta = 25°C)

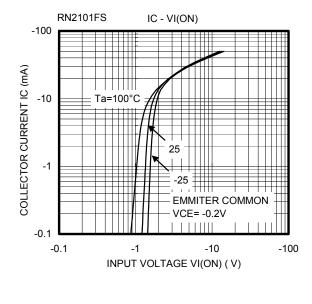
Characteristics		Symbol	Rating	Unit	
Collector-base voltage	RN2101FS~2106FS	V_{CBO}	-20	V	
Collector-emitter voltage	KINZ 1011 3 - 2 1001 3	V_{CEO}	-20	V	
Emitter-base voltage	RN2101FS~2104FS	V _{EBO}	-10	V	
	RN2105FS, 2106FS	VEBO	-5		
Collector current		IC	-50	mA	
Collector power dissipation	RN2101FS~2106FS	PC	50	mW	
Junction temperature	KIN2101F3*2100F3	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

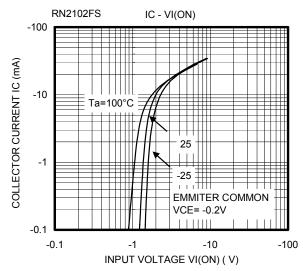


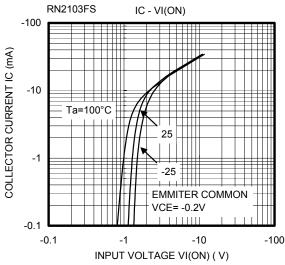
Electrical Characteristics (Ta = 25°C)

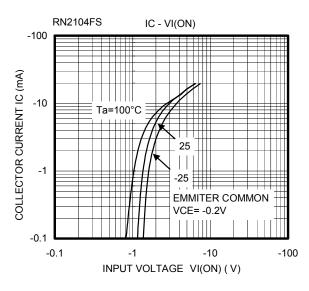
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2101FS~2106FS	I _{CBO}	$V_{CB} = -20 \text{ V}, I_E = 0$	_	_	-100	nA
		I _{CEO}	$V_{CE} = -20 \text{ V}, I_B = 0$	_	_	-500	
Emitter cut-off current	RN2101FS	- ІЕВО	$V_{EB} = -10 \text{ V}, I_C = 0$	-0.89	_	-1.33	- mA
	RN2102FS			-0.41	_	-0.63	
	RN2103FS			-0.18	_	-0.29	
	RN2104FS			-0.088	_	-0.133	
	RN2105FS		$V_{EB} = -5 \text{ V}, I_C = 0$	-0.085	_	-0.127	
	RN2106FS			-0.08	_	-0.121	
DC current gain	RN2101FS		V _{CE} = -5 V, I _C = -10 mA	30	_	_	
	RN2102FS			60	_	_	
	RN2103FS			100	_	_	
	RN2104FS	- h _{FE}		120	_	_	
	RN2105FS			120	_	_	
	RN2106FS			120	_	_	
Collector-emitter saturation voltage	RN2101FS~2106FS	V _{CE (sat)}	$I_C = -5 \text{ mA},$ $I_B = -0.25 \text{ mA}$	_	_	-0.15	٧
Input voltage (ON)	RN2101FS	V _I (ON)	V _{CE} = -0.2 V, I _C = -5 mA	-1.0	_	-2.0	V
	RN2102FS			-1.0	_	-2.2	
	RN2103FS			-1.1	_	-2.7	
	RN2104FS			-1.2	_	-3.6	
	RN2105FS			-0.6	_	-1.1	
	RN2106FS			-0.6	_	-1.2	
Input voltage (OFF)	RN2101FS~2104FS	V _{I (OFF)}	$V_{CE} = -5 \text{ V},$ $I_{C} = -0.1 \text{ mA}$	-0.8	_	-1.5	٧
	RN2105FS, 2106FS			-0.4	_	-0.8	
Collector output capacitance	RN2101FS~2106FS	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0,$ $f = 1 \text{ MHz}$	_	1.2		pF
Input resistor	RN2101FS		_	3.76	4.7	5.64	kΩ
	RN2102FS	- - R1 -		8	10	12	
	RN2103FS			17.6	22	26.4	
	RN2104FS			37.6	47	56.4	
	RN2105FS			1.76	2.2	2.64	
	RN2106FS			3.76	4.7	5.64	
Resistor ratio	RN2101FS~2104FS	R1/R2	_	0.8	1.0	1.2	
	RN2105FS			0.0376	0.0468	0.0562	
	RN2106FS			0.08	0.1	0.12	

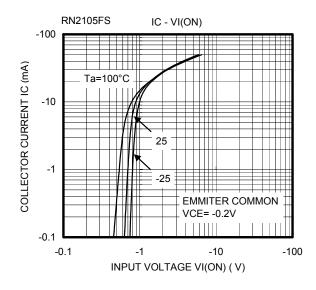
2

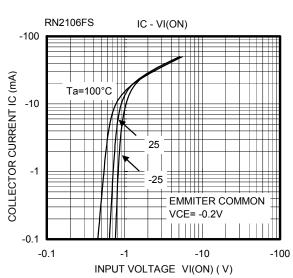


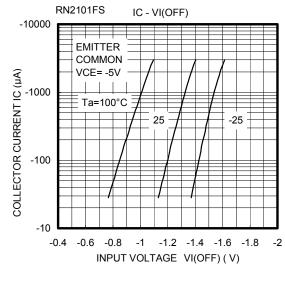


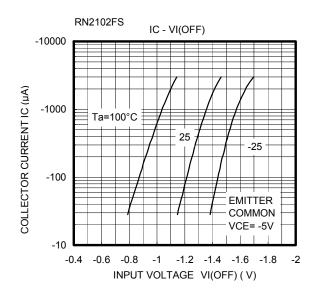


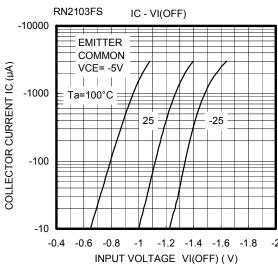


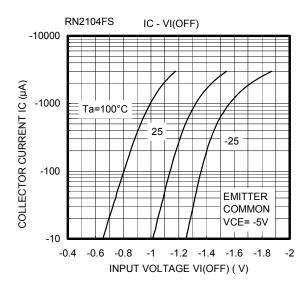


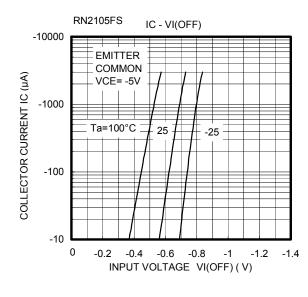


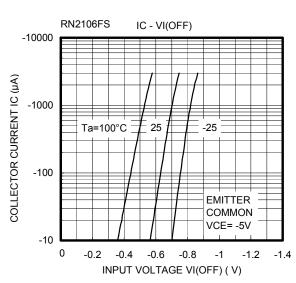




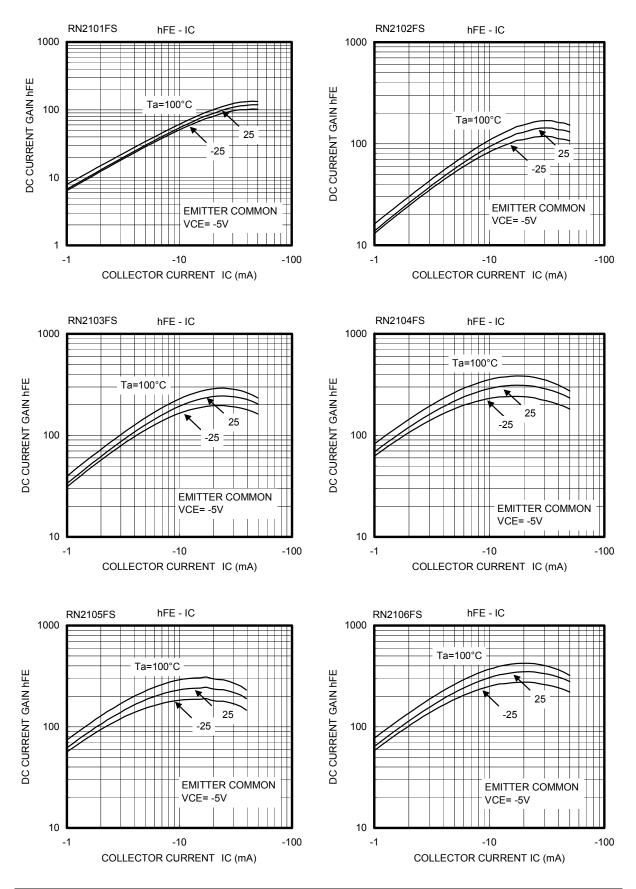




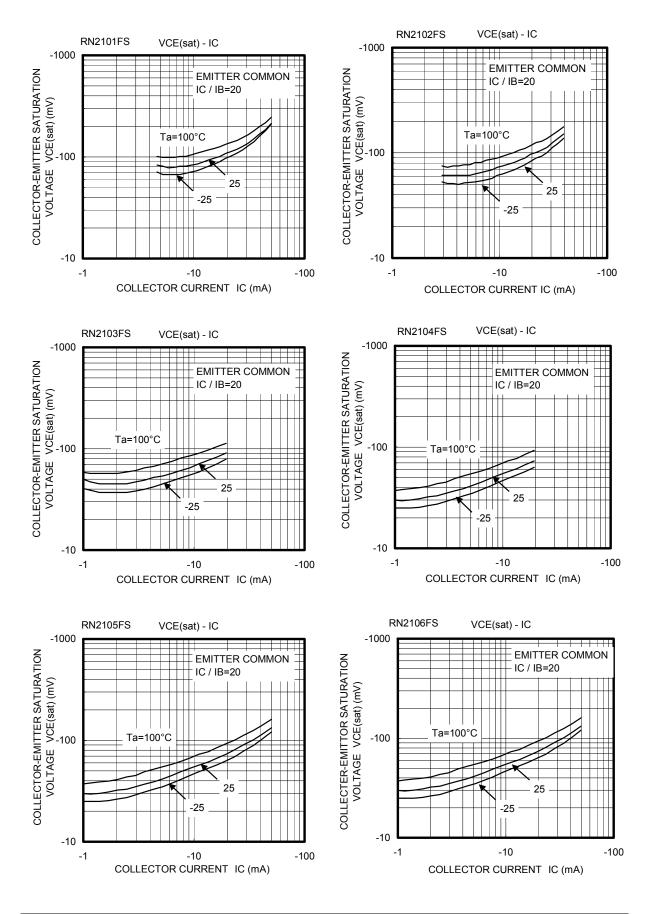


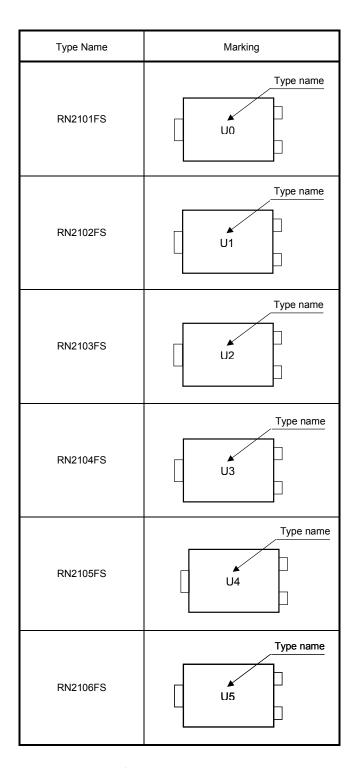


4



5 2004-02-27





HANDLING PRECAUTION

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

RESTRICTIONS ON PRODUCT USE

030619EAA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
 may result from its use. No license is granted by implication or otherwise under any patent or patent rights of
 TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.